



June 2016



FJV3114R — NPN Epitaxial Silicon Transistor with Bias Resistor

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Features

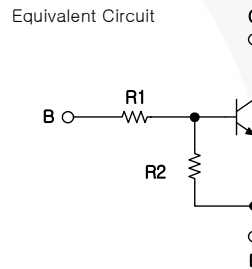
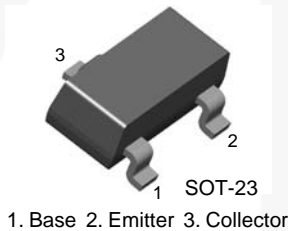
- 100 mA Output Current Capability
- Built-in Bias Resistor ($R_1 = 4.7\text{ k}\Omega$, $R_2 = 47\text{ k}\Omega$)

Application

- Switching, Interface, and Driver Circuits
- Inverters
- Digital Applications in Industrial Segments

Description

Transistors with built-in resistors can be excellent space- and cost-saving solutions by reducing component count and simplifying circuit design.



Ordering Information

| Part Number | Top Mark | Package | Packing Method |
|-------------|----------|-----------|----------------|
| FJV3114RMTF | R34 | SOT-23 3L | Tape and Reel |

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

| Symbol | Parameter | Value | Unit |
|-----------|---------------------------|------------|------------------|
| V_{CBO} | Collector-Base Voltage | 50 | V |
| V_{CEO} | Collector-Emitter Voltage | 50 | V |
| V_{EBO} | Emitter-Base Voltage | 10 | V |
| I_C | Collector Current | 100 | mA |
| T_J | Junction Temperature | 150 | $^\circ\text{C}$ |
| T_{STG} | Storage Temperature | -55 to 150 | $^\circ\text{C}$ |

Thermal Characteristics⁽¹⁾

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

| Symbol | Parameter | Value | Unit |
|-----------------|---|-------|---------------------------|
| P_D | Power Dissipation | 200 | mW |
| | Derate Above $T_A = 25^\circ\text{C}$ | 1.60 | mW/ $^\circ\text{C}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 625 | $^\circ\text{C}/\text{W}$ |

Note:

1. FR-4 76 x 114 x 0.6T mm³ (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|-------------------|--------------------------------------|--|------|------|------|---------------|
| BV_{CBO} | Collector-Base Breakdown Voltage | $I_C = 10 \mu\text{A}$, $I_E = 0$ | 50 | | | V |
| BV_{CEO} | Collector-Emitter Breakdown Voltage | $I_C = 100 \mu\text{A}$, $I_B = 0$ | 50 | | | V |
| I_{CBO} | Collector Cut-Off Current | $V_{CB} = 40 \text{ V}$, $I_E = 0$ | | | 0.1 | μA |
| h_{FE} | DC Current Gain | $V_{CE} = 5 \text{ V}$, $I_C = 5 \text{ mA}$ | 68 | | | |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = 10 \text{ mA}$, $I_B = 0.5 \text{ mA}$ | | | 0.3 | V |
| f_T | Current Gain Bandwidth Product | $V_{CE} = 10 \text{ V}$, $I_C = 5 \text{ mA}$ | | 250 | | MHz |
| C_{ob} | Output Capacitance | $V_{CB} = 10 \text{ V}$, $I_E = 0$, $f = 1.0 \text{ MHz}$ | | 3.7 | | pF |
| $V_I(\text{off})$ | Input-Off Voltage | $V_{CE} = 5 \text{ V}$, $I_C = 100 \mu\text{A}$ | | | 0.5 | V |
| $V_I(\text{on})$ | Input-On Voltage | $V_{CE} = 0.2 \text{ V}$, $I_C = 5 \text{ mA}$ | 1.3 | | | V |
| R_1 | Input Resistor | | 3.2 | 4.7 | 6.2 | k Ω |
| R_1/R_2 | Resistor Ratio | | 0.09 | 0.10 | 0.11 | |

Typical Performance Characteristics

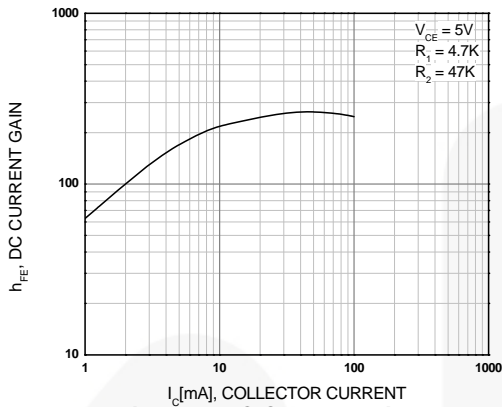


Figure 1. DC Current Gain

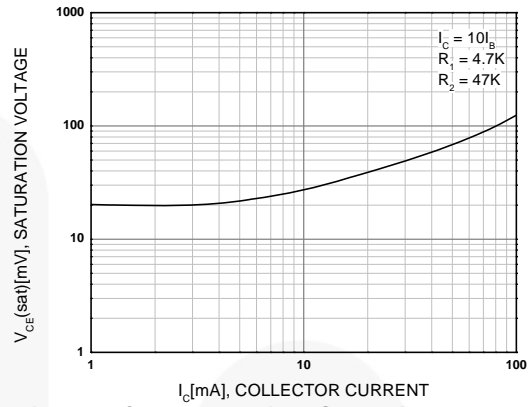


Figure 2. Collector-Emitter Saturation Voltage

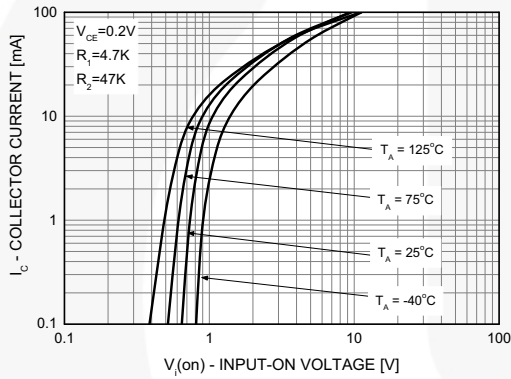


Figure 3. Input-On Voltage

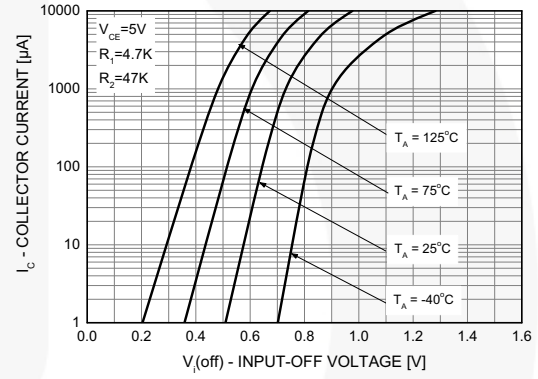


Figure 4. Collector Current vs. Input Off Voltage

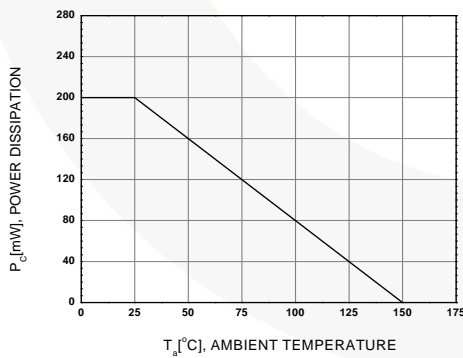


Figure 5. Power Derating



LAND PATTERN
RECOMMENDATION



SEE DETAIL A



DETAIL A
SCALE: 2X

NOTES: UNLESS OTHERWISE SPECIFIED

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